# NSN 5961-01-020-1727

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#### Inclosure Material:

Metal

## **Overall Length:**

Between 1.510 inches and 1.550 inches

## **Overall Height:**

Between 0.250 inches and 0.300 inches

#### **Overall Width:**

1.050 inches

### **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### H-1

### Electrode Internally-electrically Connected To Case:

Collector

### Internal Junction Configuration:

Npn

### **Mounting Method:**

Unthreaded hole

# **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

90.0 collector to emitter voltage/static/base open

# **Current Rating Per Characteristic:**

50.00 amperes source cutoff current

# Power Rating Per Characteristic:

140.0 watts small-signal input power, common-collector absolute

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

#### **Terminal Type And Quantity:**

2 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0